

II. CLAIM AMENDMENTS

1. (Currently Amended) A laser being tunable in wavelength cavity, comprising:

- a first cavity end mirrorreflecting unit (10) and a second cavity end mirrorreflecting unit (20), both mirrorreflecting units being arranged to at least partially reflect an incident beam (100) of electromagnetic radiation towards each other,
- an optical path of said beam of electromagnetic radiation within said a cavity, which is defined in length by said first (10) and second cavity end mirrorreflecting units (20),
- a dispersive device (50), which is arranged, such that a portion of said optical path of said beam (100) of electromagnetic radiation traverses through said dispersive device (50),

wherein said dispersive device (50) comprises a dispersive characteristic representing a functional dependence of an optical path length of said portion with respect to wavelength of said electromagnetic radiation, wherein said optical path length increases with an increasing wavelength of said electromagnetic radiation.

2. (Currently Amended) The laser being tunable in wavelength cavity according to claim 1,

wherein said functional dependence of said dispersive characteristic is designed to admit exactly one single mode of electromagnetic radiation to develop within said cavity.

3. (Currently Amended) The laser being tunable in wavelength cavity according to claim 1,

wherein said functional dependence of said dispersive characteristic is designed such that said optical path length within said cavity is the same for any two different wavelengths of said electromagnetic radiation at least within a limited wavelength range.

4. (Currently Amended) The laser being tunable in wavelength cavity according to

claim 1-~~or any one of the above claims~~,

further comprising a gain medium-(50) for generating said electromagnetic radiation, said gain medium-(50) comprising a back facet, which is identical to said ~~first cavity end mirrorreflecting unit-(10)~~, and a front surface-(51), said gain medium-(50) emitting said beam-(100) through said front surface-(51) towards said ~~second cavity end mirrorreflecting unit-(20)~~.

5. (Currently Amended) The laser being tunable in wavelength cavity according to claim 1-~~or any one of the above claims~~,

wherein said dispersive device-(30) represents at least a part of said ~~second cavity end mirrorreflecting unit-(20)~~.

6. (Currently Amended) The laser being tunable in wavelength cavity according to claim 1-~~or any one of the above claims~~,

further comprising a lens-(40) for collimating said beam-(100) emitted from said gain medium-(50) along said optical path towards said ~~second cavity end mirrorreflecting unit-(20)~~.

7. (Currently Amended) The laser being tunable in wavelength cavity according to claim 6,

wherein said dispersive device-(30) represents at least a part of said lens.

8. (Currently Amended) The laser being tunable in wavelength cavity according to claim 13-~~or any one of the above claims~~,

further comprising a wavelength tunable filter-(60) for selecting a wavelength range of a spectral distribution of said electromagnetic radiation comprising one resonance mode out of the set of resonance modes of said cavity.

9. (Currently Amended) The laser being tunable in wavelength cavity according to claim 7-1-~~or any one of the above claims~~,

wherein either one of said gain medium-(50) or said ~~second cavity end mirrorreflecting unit-(20)~~ is movable in the direction of the optical path of said beam-(100) for adjusting said optical path length of said cavity to said selected wavelength range provided by said wavelength tunable filter-(60).

10. (Currently Amended) The laser being tunable in wavelength cavity according to claim 8,

wherein said wavelength tunable filter-(60) comprises a grating for diffracting and redirecting said beam-(100) of electromagnetic radiation, the cavity being either one of a Littrow cavity or a Littmann cavity.

11. (Cancelled)

12. (Currently Amended) The laser being tunable in wavelength cavity according to ~~claim 1 or any one of the above claims~~,

wherein said dispersive device-(50) comprises one or more materials of the group comprising:

- semiconductor material epitactically grown on a substrate material, said semiconductor material and said substrate material being either combination of: AlGaAs and GaAs, AlGaNp and GaAs, InGaAsP and InP, or AlGaN and GaN, respectively.
- a semiconductor material deposited on a substrate material in a vapor deposition step, said semiconductor material being one of a group comprising: Si, Ge.
- a semiconductor material structured as bulk material being one of Si, GaAs, and InP.
- a dielectric material being of SiO_2 , TiO , Ta_2O_5 , SiN .
- a polymer material of a group comprising PMMA.

13. (Currently Amended) The laser being tunable in wavelength cavity according to ~~claim 4 or any one of the above claims~~, comprising at least one of the features:

wherein said gain medium-(50) is a linear source optical amplifier;

said dispersive device is integrated within said gain medium.

14. (Cancelled)